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Inclosure Material:

Metal

Overall Length:

1.252 inches

Overall Height:

0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 breakdown voltage, collector-to-base, emitter open and 6.0 breakdown voltage, collector-to-emitter, base open and 300.0

breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

5.00 amperes source cutoff current and 1.00 amperes source cutoff current

Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector

Transfer Ratio:

100.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

2 pin and 1 case

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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